

# Ruttonsha International Rectifier Ltd. **HIGH POWER THYRISTOR**

RUTTONSHA

### **INVERTER GRADE THYRISTOR**

# Hockey Puk Version **K-PUK SERIES 1050PK**

Type: 1050 PK140 F To 1050 PK 200 F

### Features

- Low Switching loss at high frequency.
- 45  $\mu$ s maximum turn-off time with feedback diode.
- Involute, interdigitate gate

## **Typical Applications**

- Inverters
- Choppers
- Induction heating
- All type of forced-Commutated converters





Case Style A-24 (K-PUK)

# Major Ratings and Characteristics :-

PARAMETERS	1050PKF	UNITS	
I <sub>T(AV)</sub>	1050	A	
@T <sub>hs</sub>	55	°C	
I T(RMS)	1648	Α	
@T <sub>hs</sub>	55	°C	
I <sub>тsm</sub> @50Hz	12,000	A	
l <sup>2</sup> t	720	KA <sup>2</sup> s	
V <sub>DRM</sub> /V <sub>RRM</sub>	1400 to 2000	V	
T <sub>q</sub> typical	40 to 45	μS	
TJ	125	°C	

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#### **Electrical Specifications**

#### Voltage Ratings

Type Number	Voltage Code	V <sub>DRM</sub> /V <sub>RRM</sub> , max repetitive peak voltage	V <sub>RSM</sub> ,maximum non- repetitive peak voltage	I <sub>DRM</sub> /I <sub>RRM</sub> max. mA	
		V	V	25°c	125°c
	140	1400	1500	60	60
1050PKF	160	1600	1700	60	60
	180	1800	1900	60	60
	200	2000	2100	60	60

#### **On-state Conduction**

	Parameter	1050PKF	Units	Conditions
I <sub>T(AV)</sub>	Max. average on-state current	1050	А	180° conduction, half sine wave
382 6	@ Heatsink temperature	55	°C	double side cooled
IT(RMS)	Max RMS on-state current	1648	А	DC @ 55°C heatsink temperature double side cooled
V <sub>TM</sub>	Max. on-state voltage	2.10	V	$I_T = 1000A, T_J = T_J max., Duty Cycle \le 0.01\%$

#### Switching

	Parameter	1050PKF	Units	Conditions
di/dt	Max. Repetitive rate of rise of turned-on current	100	A/μs	$T_J = T_J max., V_{DRM} = rated V_{DRM}$
t <sub>d</sub>	Typical delay time	1.5	μs	Switching from 140V, 20V, 10 ohm Gate 0.5 $\mu$ s rise time, T <sub>J</sub> = 25 °C
t <sub>q</sub>	Typical turn-off time	40 to 45	μs	$T_J=T_J max.$ , $I_T = 1000A$ , $V_R = 50V$ , di/dt=25A/us 80 % $V_{DRM}$ Reapplied, dv/dt = 400 V / $\mu$ s, Gate bias = open During Turn-Off, Interval = 0V, 100 ohm, Duty Cycle $\leq 0.01\%$
Vo	Threshould Voltage	1.57	٧	T <sub>J</sub> =T <sub>J</sub> max.
r <sub>T</sub>	Forward slop resistance	0.40		T <sub>J</sub> =T <sub>J</sub> max.

#### Blocking

Fra	Parameter	1050PKF	Units	Conditions
the second second states the	Vin. critical rate of rise of off-state voltage	500	V/µs	$T_J = T_J max$ . linear to 80% rated $V_{DRM}$
	Max. peak reverse and off-state eakage current	60	mA	$T_J = T_J max.$ , rated $V_{DRM} / V_{RRM}$ applied

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#### Triggering

	Parameter	1050PKF	Units	Conditions
P <sub>GM</sub>	Maximum peak gate power	100	W	$T_J = T_J max., t_p \le 5 ms$
P <sub>G(AV</sub>	, Maximum average gate power	5	W	$T_J = T_J max., f = 60Hz,$
І <sub>GT</sub>	Max. DC gate current required to trigger	200	mA	$T_J = 25^{\circ}C, V_D = 10 V dc$ $R_L = 3 ohm$
V <sub>GT</sub>	Max. DC gate voltage required to trigger	3.0	v	$T_{J} = 25^{\circ}C, V_{D} = 10 V dc$ $R_{L} = 3 ohm$

#### **Thermal and Mechanical Specifications**

	Parameter	1050PKF	Units	Conditions
TJ	Max.operating temperature range	125	°C	
T <sub>stg</sub>	Max.storage temperature range	- 40 to +125	°C	
R <sub>thJ-hs</sub>	Max. thermal resistance,			
	junction to Heat sink	0.025	°C/W	DC operation double side cooled
F	Mounting force, ±10%	24.5	KN	

